

➤ Product specification

Product Name	PR-B20N
Type	Infrared beam type
Output	Transistor Output(Open Collector)
Power	+12Vdc / 0.5A
Usage Environment Temperature	0 ~ +50℃
Detection Height	50mm
Detection Width	20φ
Materials Which Can Be Detected	<ul style="list-style-type: none"> · Detection of transparent material: possible · Edge detection: possible · Detection of opaque material: possible · Line detection: impossible
Weight	1Kg (Excluding ARM 0.65Kg)

